



# INTERNATIONAL CENTRE FOR APPLIED SCIENCES

MAHE, MANIPAL

B.Sc. (Applied Sciences) in Engg.

End – Semester Theory Examinations – Nov./ Dec. 2020

III SEMESTER - ANALOG ELECTRONIC CIRCUITS (IEC 231)

(Branch: CS)

Time: 3 Hours

Date: 19 November 2020

Max. Marks: 100

- ✓ Answer Any Five Full questions.
- ✓ Missing data, if any, may be suitably assumed

1A. Draw the circuit diagram of common emitter configuration using NPN transistor. Draw and explain the input and output characteristics. Indicate cut-off, saturation and active regions. 10M

1B. The CS stage shown in **FIG 1B** must achieve a voltage gain  $A_V = 15$  at a bias current of 0.5mA. If  $\lambda_1 = 0.15/V$  and  $\lambda_2 = 0.05/V$ , determine the required value of  $(W/L)_2$ .  
Assume  $\mu_p C_{OX} = 100 \frac{\mu A}{V^2}$

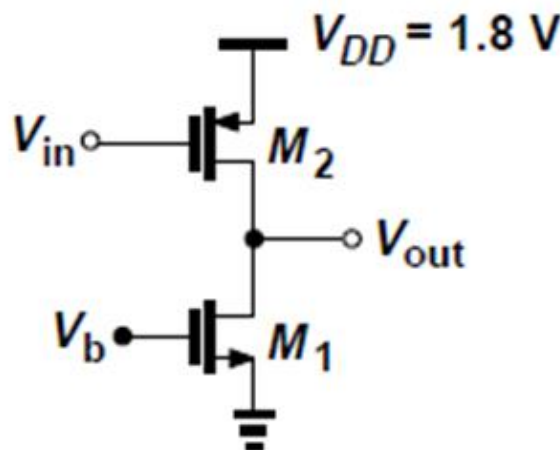
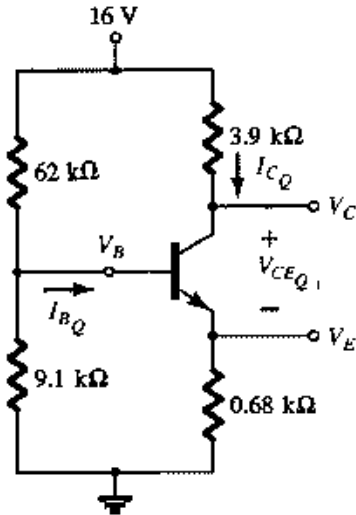


Fig 1B

10M

2A. Draw the circuit diagram of a common source stage using NMOSFET, with drain resistance  $R_D$ . Draw the small signal model of the circuit. Obtain the expression for the voltage gain and output resistance. Assume  $\lambda \neq 0$ . 10M

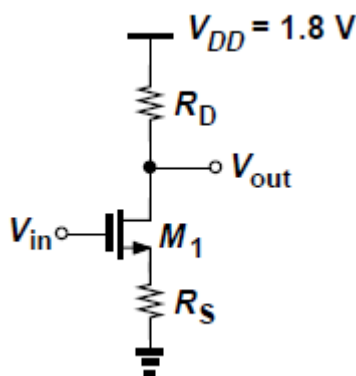
- 2B. Determine  $I_B$ ,  $I_C$ ,  $I_E$ ,  $V_{CE}$ ,  $V_B$ ,  $V_C$  and  $V_E$  for the voltage divider configuration shown in **Fig 2B** given that  $\beta=80$ . Assume  $V_{BE}=0.7V$ . What is the region of operation? Neglect  $I_{CO}$ .



**Fig 2B**

10M

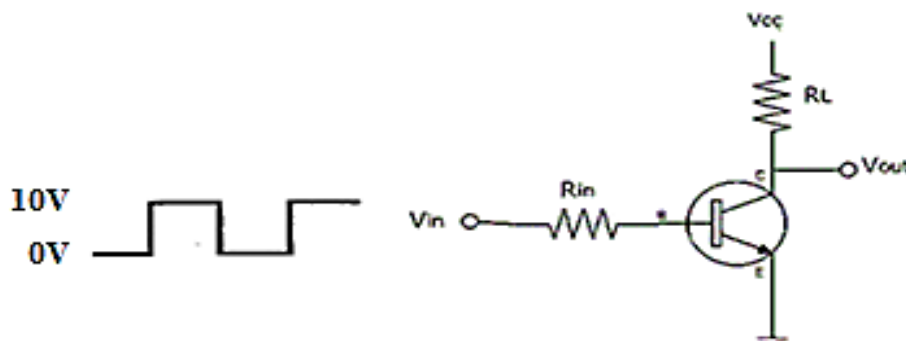
- 3A. Draw the circuit diagram of a common source stage using a NMOSFET, with NMOS diode connected as load. Draw the small signal model of the circuit. Obtain the expression for the voltage gain and output resistance. Assume  $\lambda \neq 0$ . 10M
- 3B. State and explain Millers theorem with an illustration. Explain any one application of this theorem with necessary circuit 10M
- 4A. Draw the circuit diagram of RC coupled amplifier with feedback using NPN transistor. Mention the function of each component. Explain the working at low, medium and high frequencies. 10M
- 4B. The degenerative CS stage of **Fig. 4B** must provide a voltage gain of 4 with a bias current of 1 mA. Assume a drop of 200 mV across  $R_S$  and  $\lambda=0$ . If  $R_D=1K\Omega$ , determine the required value of  $W/L$ . Does the transistor operate in Saturation for this choice of  $W/L$ ? Assume  $\mu_n C_{OX} = 200 \frac{\mu A}{V^2}$ ,  $V_{th} = 0.4V$ .



**Fig. 4B**

10M

- 5A. Draw the circuit diagram of a crystal oscillator and explain the working. Mention any two advantages of Crystal oscillators. 10M
- 5B. Draw the circuit diagram of a common source stage using a NMOSFET, with a source degeneration resistance  $R_s$ . Draw the small signal model of the circuit. Obtain the expression for the voltage gain (Assume  $\lambda=0$ ) and output resistance with the assumption  $\lambda \neq 0$ . 10M
- 6A. Draw the circuit diagram of a common source stage using NMOSFET, with a PMOS current source. Draw the small signal model of the circuit. Obtain the expression for the voltage gain and output resistance. Assume  $\lambda \neq 0$ . 10M
- 6B. With the help of a circuit diagram, explain the working of transformer coupled Class B push pull power amplifier. Derive an expression for the maximum power efficiency. Mention one drawback of this amplifier. 10M
- 7A. Draw the block schematic of i) Voltage shunt ii) Current series feedback amplifiers. What is the effect of series and shunt feedback on the input and output resistance of an amplifier? 10M
- 7B. For the transistor (Silicon) circuit shown in Fig.7B,  $R_{in} = 100K\Omega$ ,  $R_L = 820\Omega$  and  $V_{CC} = 10V$ . Assume  $V_{BE, sat}=0.8V$  and  $V_{CEsat} = 0.2V$ . Find the minimum base and collector current required in order to keep the transistor in saturation. Neglect  $I_{CBO}$ . Explain briefly the working of the circuit and draw the output waveform. 10M



**Fig. 7B**

10M

- 8 Explain the following: 4x5=20M
- Early effect in BJT
  - Channel length modulation in MOSFET
  - Advantages and disadvantages of Positive and Negative feedback.
  - Piezoelectric effect in crystals.

\*\*\*\*\*